

# NB4N527S

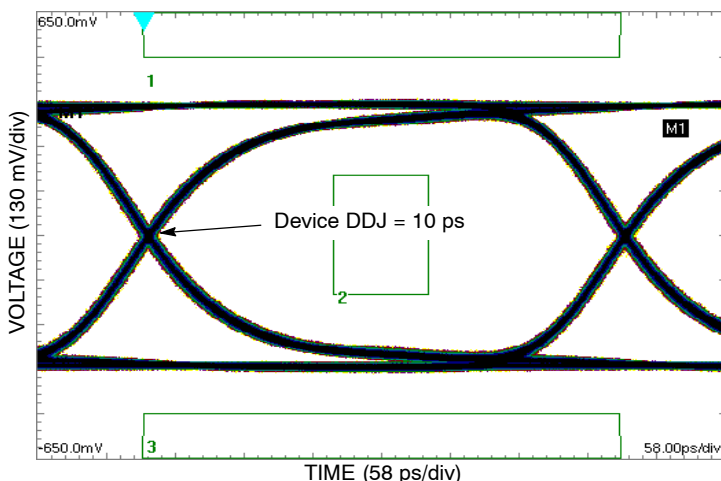
## 3.3V, 2.5Gb/s Dual AnyLevel™ to LVDS Receiver/Driver/Buffer/Translator with Internal Input Termination

NB4N527S is a clock or data Receiver/Driver/Buffer/Translator capable of translating AnyLevel™ input signal (LVPECL, CML, HSTL, LVDS, or LVTTTL/LVCMOS) to LVDS. Depending on the distance, noise immunity of the system design, and transmission line media, this device will receive, drive or translate data or clock signals up to 2.5 Gb/s or 1.5 GHz, respectively.

The NB4N527S has a wide input common mode range of  $GND + 50\text{ mV}$  to  $V_{CC} - 50\text{ mV}$  combined with two  $50\ \Omega$  internal termination resistors and is ideal for translating differential or single-ended data or clock signals to 350 mV typical LVDS output levels without use of any additional external components (Figure 6).

The device is offered in a small 3 mm x 3 mm QFN-16 package. NB4N527S is targeted for data, wireless and telecom applications as well as high speed logic interface where jitter and package size are main requirements. Application notes, models, and support documentation are available on [www.onsemi.com](http://www.onsemi.com).

- Maximum Input Clock Frequency up to 1.5 GHz
- Maximum Input Data Rate up to 2.5 Gb/s (Figure 5)
- 470 ps Maximum Propagation Delay
- 1 ps Maximum RMS Jitter
- 140 ps Maximum Rise/Fall Times
- Single Power Supply;  $V_{CC} = 3.3\text{ V} \pm 10\%$
- Temperature Compensated TIA/EIA-644 Compliant LVDS Outputs
- Internal  $50\ \Omega$  Termination Resistor per Input Pin
- $GND + 50\text{ mV}$  to  $V_{CC} - 50\text{ mV}$   $V_{CMR}$  Range
- Pb-Free Packages are Available



**Figure 2. Typical Output Waveform at 2.488 Gb/s with PRBS  $2^{23}-1$  ( $V_{INPP} = 400\text{ mV}$ ; Input Signal DDJ = 14 ps)**



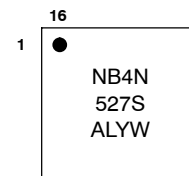
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### MARKING DIAGRAM\*

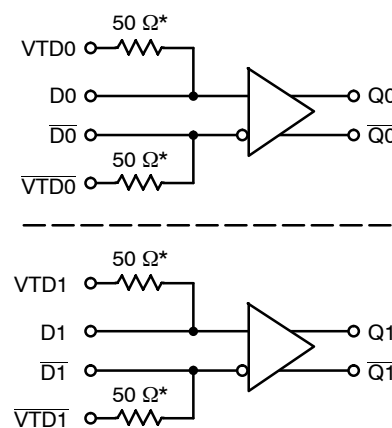


**QFN-16  
MN SUFFIX  
CASE 485G**



A	= Assembly Location
L	= Wafer Lot
Y	= Year
W	= Work Week

\*For additional marking information, refer to Application Note AND8002/D.



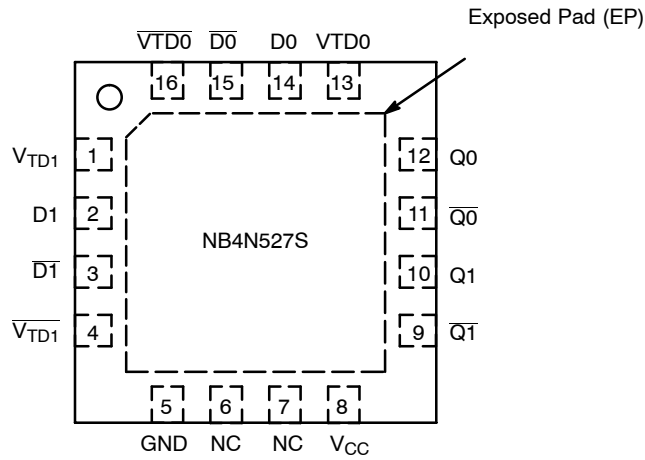
**Figure 1. Functional Block Diagram**

\* $R_{TIN}$

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

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**Figure 3. Pin Configuration** (Top View)

**Table 1. PIN DESCRIPTION**

Pin	Name	I/O	Description
1	VTD1	–	Internal 50 $\Omega$ termination pin for D1. ( $R_{TIN}$ )
2	D1	LVPECL, CML, LVDS, LVCMOS, LVTTTL, HSTL	Noninverted differential clock/data D1 input (Note 1).
3	D1	LVPECL, CML, LVDS, LVCMOS, LVTTTL, HSTL	Inverted differential clock/data D1 input (Note 1).
4	VTD1	–	Internal 50 $\Omega$ termination pin for D1. ( $R_{TIN}$ )
5	GND	–	0 V. Ground.
6, 7	NC		No connect.
8	VCC		Positive Supply Voltage.
9	Q1	LVDS Output	Inverted D1 output. Typically loaded with 100 $\Omega$ receiver termination resistor across differential pair.
10	Q1	LVDS Output	Noninverted D1 output. Typically loaded with 100 $\Omega$ receiver termination resistor across differential pair.
11	Q0	LVDS Output	Inverted D0 output. Typically loaded with 100 $\Omega$ receiver termination resistor across differential pair.
12	Q0	LVDS Output	Noninverted D0 output. Typically loaded with 100 $\Omega$ receiver termination resistor across differential pair.
13	VTD0	–	Internal 50 $\Omega$ termination pin for D0.
14	D0	LVPECL, CML, LVDS, LVCMOS, LVTTTL, HSTL	Noninverted differential clock/data D0 input (Note 1).
15	D0	LVPECL, CML, LVDS, LVCMOS, LVTTTL, HSTL	Inverted differential clock/data D0 input (Note 1).
16	VTD0	–	Internal 50 $\Omega$ termination pin for D0.
EP			Exposed pad. EP on the package bottom is thermally connected to the die improved heat transfer out of package. The pad is not electrically connected to the die, but is recommended to be soldered to GND on the PCB.

1. In the differential configuration when the input termination pins(VTD0/VTD0, VTD1/ VTD1) are connected to a common termination voltage or left open, and if no signal is applied on D0/D0, D1/D1 input, then the device will be susceptible to self-oscillation.

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**Table 2. ATTRIBUTES**

Characteristics	Value
Moisture Sensitivity (Note 2)	Level 1
Flammability Rating	Oxygen Index: 28 to 34 UL 94 V-0 @ 0.125 in
ESD Protection	Human Body Model Machine Model Charged Device Model
Transistor Count	281
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test	

2. For additional information, see Application Note AND8003/D.

**Table 3. MAXIMUM RATINGS**

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V <sub>CC</sub>	Positive Power Supply	GND = 0 V		3.8	V
V <sub>I</sub>	Positive Input	GND = 0 V	V <sub>I</sub> = V <sub>CC</sub>	3.8	V
I <sub>IN</sub>	Input Current Through R <sub>T</sub> (50 Ω Resistor)	Static Surge		35 70	mA mA
I <sub>OSC</sub>	Output Short Circuit Current Line-to-Line (Q to $\bar{Q}$ ) Line-to-End (Q or $\bar{Q}$ to GND)	Q or $\bar{Q}$ to GND Q to $\bar{Q}$	Continuous Continuous	12 24	mA
T <sub>A</sub>	Operating Temperature Range	QFN-16		-40 to +85	°C
T <sub>stg</sub>	Storage Temperature Range			-65 to +150	°C
θ <sub>JA</sub>	Thermal Resistance (Junction-to-Ambient) (Note 3)	0 lfpm 500 lfpm	QFN-16 QFN-16	41.6 35.2	°C/W °C/W
θ <sub>JC</sub>	Thermal Resistance (Junction-to-Case)	1S2P (Note 3)	QFN-16	4.0	°C/W
T <sub>sol</sub>	Wave Solder	Pb Pb-Free	<3 Sec @ 248°C <3 Sec @ 260°C	265 265	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

3. JEDEC standard multilayer board – 1S2P (1 signal, 2 power) with 8 filled thermal vias under exposed pad.

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**Table 4. DC CHARACTERISTICS, CLOCK INPUTS, LVDS OUTPUTS**  $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ ,  $GND = 0\text{ V}$ ,  $T_A = -40^\circ\text{C to }+85^\circ\text{C}$

Symbol	Characteristic	Min	Typ	Max	Unit
$I_{CC}$	Power Supply Current (Note 8)		40	53	mA

**DIFFERENTIAL INPUTS DRIVEN SINGLE-ENDED** (Figures 11, 12, 16, and 18)

$V_{th}$	Input Threshold Reference Voltage Range (Note 7)	$GND + 100$		$V_{CC} - 100$	mV
$V_{IH}$	Single-ended Input HIGH Voltage	$V_{th} + 100$		$V_{CC}$	mV
$V_{IL}$	Single-ended Input LOW Voltage	$GND$		$V_{th} - 100$	mV

**DIFFERENTIAL INPUTS DRIVEN DIFFERENTIALLY** (Figures 7, 8, 9, 10, 17, and 19)

$V_{IHD}$	Differential Input HIGH Voltage	100		$V_{CC}$	mV
$V_{ILD}$	Differential Input LOW Voltage	$GND$		$V_{CC} - 100$	mV
$V_{CMR}$	Input Common Mode Range (Differential Configuration)	$GND + 50$		$V_{CC} - 50$	mV
$V_{ID}$	Differential Input Voltage ( $V_{IHD} - V_{ILD}$ )	100		$V_{CC}$	mV
$R_{TIN}$	Internal Input Termination Resistor	40	50	60	$\Omega$

**LVDS OUTPUTS** (Note 4)

$V_{OD}$	Differential Output Voltage	250		450	mV
$\Delta V_{OD}$	Change in Magnitude of $V_{OD}$ for Complimentary Output States (Note 9)	0	1	25	mV
$V_{OS}$	Offset Voltage (Figure 15)	1125		1375	mV
$\Delta V_{OS}$	Change in Magnitude of $V_{OS}$ for Complimentary Output States (Note 9)	0	1	25	mV
$V_{OH}$	Output HIGH Voltage (Note 5)		1425	1600	mV
$V_{OL}$	Output LOW Voltage (Note 6)	900	1075		mV

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- LVDS outputs require 100  $\Omega$  receiver termination resistor between differential pair. See Figure 14.
- $V_{OHmax} = V_{OSmax} + \frac{1}{2} V_{ODmax}$ .
- $V_{OLmax} = V_{OSmin} - \frac{1}{2} V_{ODmax}$ .
- $V_{th}$  is applied to the complementary input when operating in single-ended mode.
- Input termination pins open,  $Dx/\bar{D}x$  at the DC level within  $V_{CMR}$  and output pins loaded with  $R_L = 100\ \Omega$  across differential.
- Parameter guaranteed by design verification not tested in production.

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**Table 5. AC CHARACTERISTICS**  $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ ,  $GND = 0 \text{ V}$ ; (Note 10)

Symbol	Characteristic	-40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
$V_{OUTPP}$	Output Voltage Amplitude (@ $V_{INPPmin}$ ) $f_{in} \leq 1.0 \text{ GHz}$ (Figure 4) $f_{in} = 1.5 \text{ GHz}$	220 200	350 300		250 200	350 300		250 200	350 300		mV
$f_{DATA}$	Maximum Operating Data Rate	1.5	2.5		1.5	2.5		1.5	2.5		Gb/s
$t_{PLH}$ , $t_{PHL}$	Differential Input to Differential Output Propagation Delay	270	370	470	270	370	470	270	370	470	ps
$t_{SKEW}$	Duty Cycle Skew (Note 11) Within Device Skew (Note 17) Device-to-Device Skew (Note 15)		8 5 30	45 25 100		8 5 30	45 25 100		8 5 30	45 25 100	ps
$t_{JITTER}$	RMS Random Clock Jitter (Note 13) $f_{in} = 1.0 \text{ GHz}$ $f_{in} = 1.5 \text{ GHz}$ Deterministic Jitter (Note 14) $f_{DATA} = 622 \text{ Mb/s}$ $f_{DATA} = 1.5 \text{ Gb/s}$ $f_{DATA} = 2.488 \text{ Gb/s}$ Crosstalk Induced Jitter (Note 16)		0.5 0.5 6 7 10 20	1 1 1 20 25 40		0.5 0.5 6 7 10 20	1 1 1 20 25 40		0.5 0.5 6 7 10 20	1 1 1 20 25 40	ps
$V_{INPP}$	Input Voltage Swing/Sensitivity (Differential Configuration) (Note 12)	100		$V_{CC}-GND$	100		$V_{CC}-GND$	100		$V_{CC}-GND$	mV
$t_r$ $t_f$	Output Rise/Fall Times @ 250 MHz (20% – 80%) $Q, \bar{Q}$	60	100	140	60	100	140	60	100	140	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

10. Measured by forcing  $V_{INPPmin}$  with 50% duty cycle clock source and  $V_{CC} - 1400 \text{ mV}$  offset. All loading with an external  $R_L = 100 \Omega$  across "D" and  $\bar{D}$  of the receiver. Input edge rates 150 ps (20%–80%).

11. See Figure 13 differential measurement of  $t_{skew} = |t_{PLH} - t_{PHL}|$  for a nominal 50% differential clock input waveform @ 250 MHz.

12. Input voltage swing is a single-ended measurement operating in differential mode.

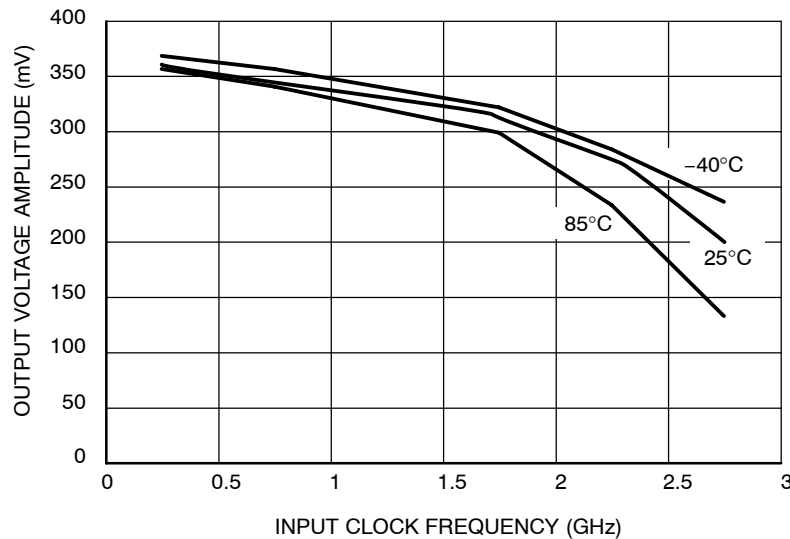
13. RMS jitter with 50% Duty Cycle clock signal at 750 MHz.

14. Deterministic jitter with input NRZ data at PRBS  $2^{23}-1$  and K28.5.

15. Skew is measured between outputs under identical transition @ 250 MHz.

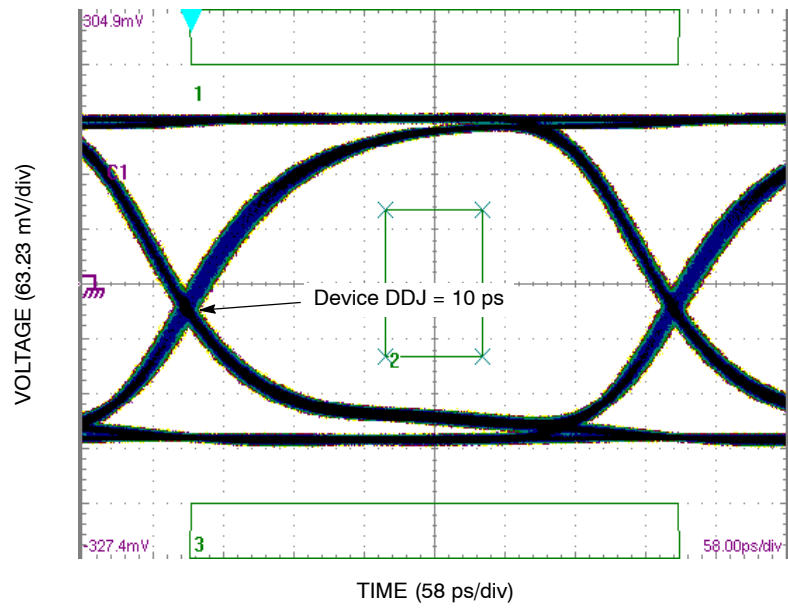
16. Crosstalk induced jitter is the additive deterministic jitter to channel one with channel two active both running at 622 Gb/s PRBS  $2^{23}-1$  as an asynchronous signals.

17. The worst case condition between  $Q0/\bar{Q}0$  and  $Q1/\bar{Q}1$  from either  $D0/\bar{D}0$  or  $D1/\bar{D}1$ , when both outputs have the same transition.

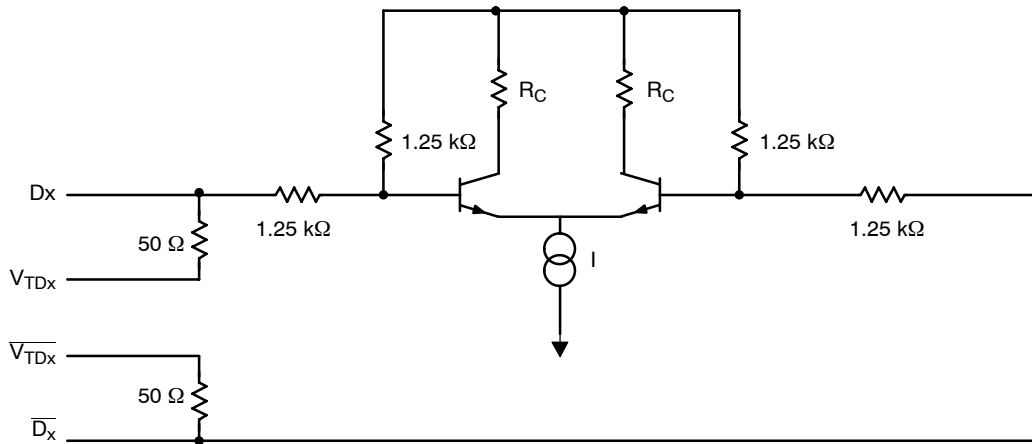


**Figure 4. Output Voltage Amplitude ( $V_{OUTPP}$ ) versus Input Clock Frequency ( $f_{in}$ ) and Temperature (@  $V_{CC} = 3.3 \text{ V}$ )**

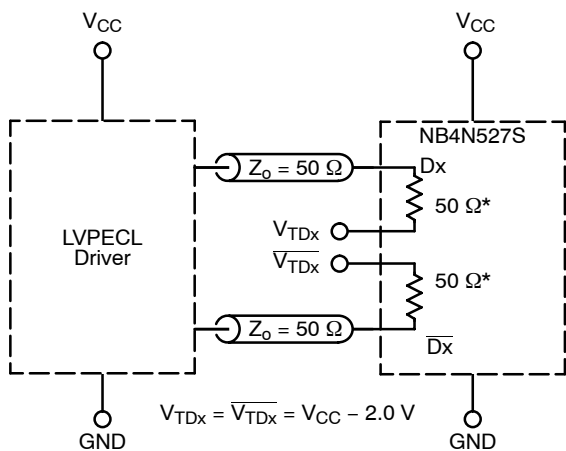
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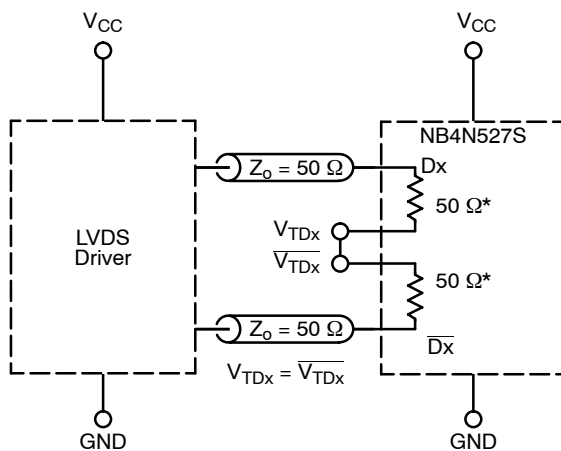
**Figure 5. Typical Output Waveform at 2.488 Gb/s with PRBS  $2^{23}-1$  and OC48 mask ( $V_{INPP} = 100$  mV; Input Signal DDJ = 14 ps)**



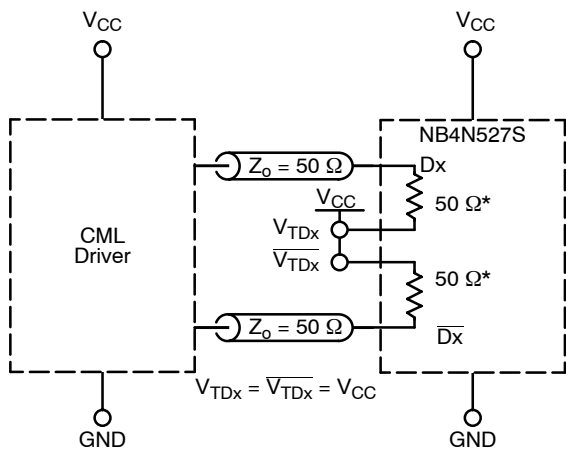
**Figure 6. Input Structure**

**NB4N527S**

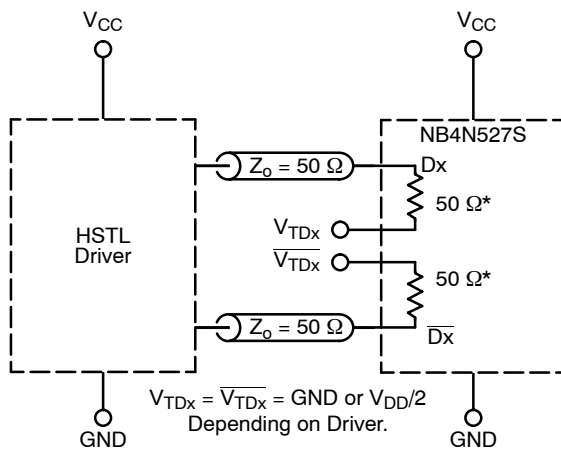
### Figure 7. LVPECL Interface



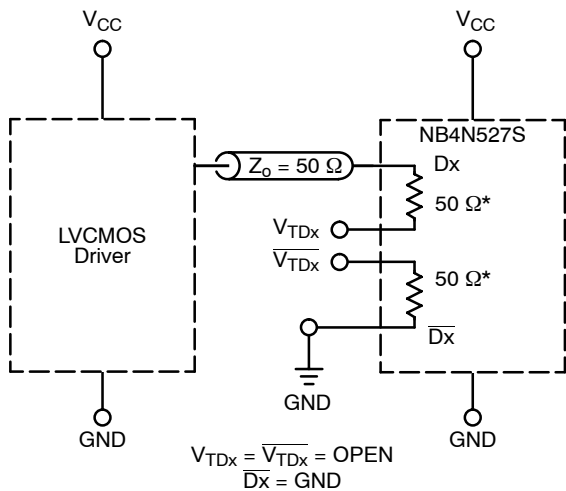
### Figure 8. LVDS Interface



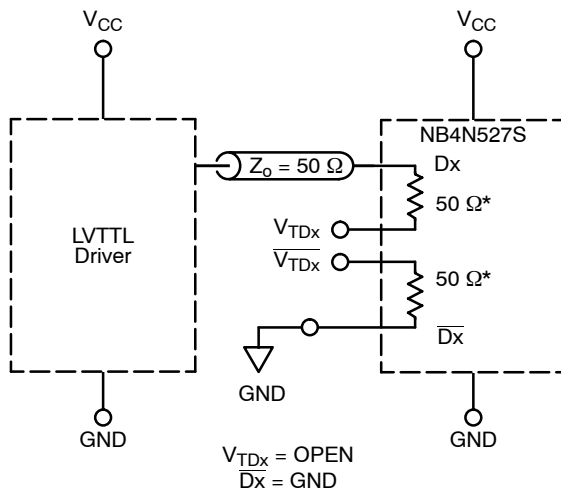
**Figure 9. Standard 50  $\Omega$  Load CML Interface**



### Figure 10. HSTL Interface



### Figure 11. LVCMOS Interface



### Figure 12. LVTTTL Interface

\*R<sub>TIN</sub>, Internal Input Termination Resistor.

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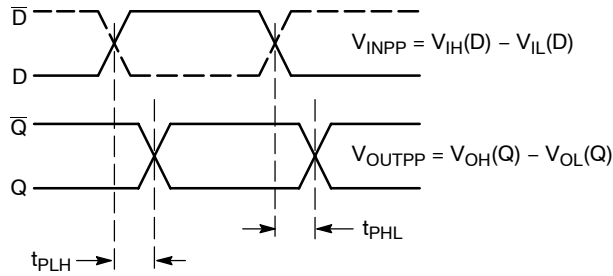


Figure 13. AC Reference Measurement

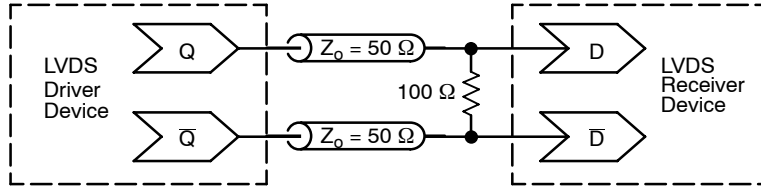


Figure 14. Typical LVDS Termination for Output Driver and Device Evaluation

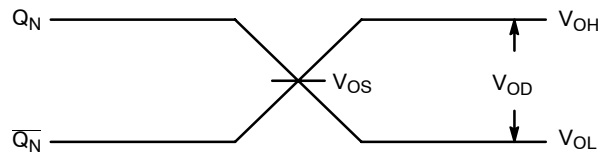


Figure 15. LVDS Output

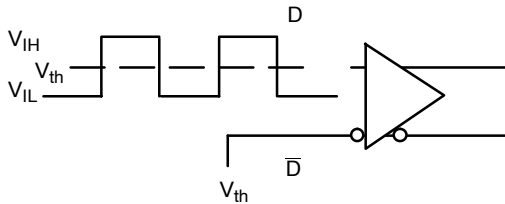


Figure 16. Differential Input Driven Single-Ended

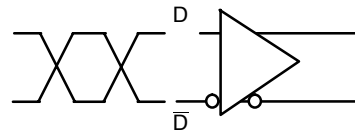


Figure 17. Differential Inputs Driven Differentially

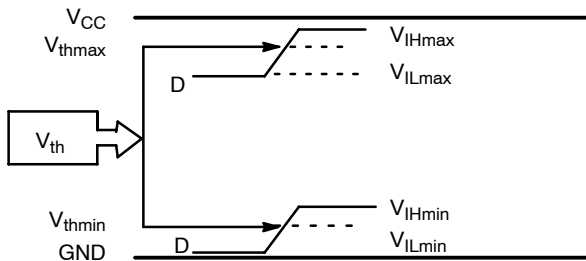


Figure 18.  $V_{th}$  Diagram

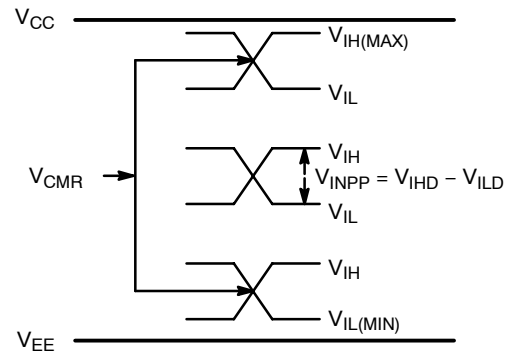


Figure 19.  $V_{CMR}$  Diagram



## NB4N527S

### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NB4N527SMN	QFN-16	123 Units / Rail
NB4N527SMNG	QFN-16 (Pb-Free)	123 Units / Rail
NB4N527SMNR2	QFN-16	3000 / Tape & Reel
NB4N527SMNR2G	QFN-16 (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.


## PACKAGE DIMENSIONS

- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSION  $b$  APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL.
  4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
  5.  $L_{max}$  CONDITION CAN NOT VIOLATE 0.2 MM MINIMUM SPACING BETWEEN LEAD TIP AND FLAG

DIM	MILLIMETER	
	MIN	MAX
A	0.80	1.00
A1	0.00	0.05
A3	0.20	REF
b	0.18	0.30
D	3.00	BSC
D2	1.65	1.85
E	3.00	BSC
E2	1.65	1.85
e	0.50	BSC
K	0.20	---
I	0.30	0.50

[illegible]

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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